

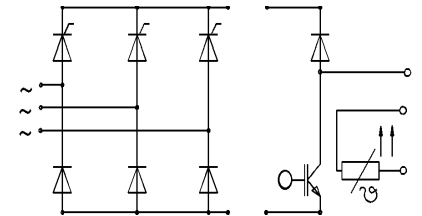
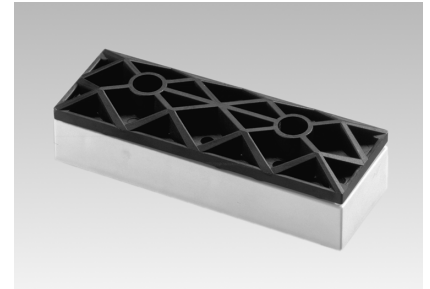
SKiiP 82 AHB 08

Absolute Maximum Ratings		Values	Units
Symbol	Conditions ¹⁾		
Bridge Rectifier			
V _{RRM}		800	V
I _D	T _{heatsink} = 80 °C	35	A
I _{FSM} /I _{TSM}	t _p = 10 ms; sin. 180 °C, T _j = 25 °C	550	A
I _{pt}	t _p = 10 ms; sin. 180 °C, T _j = 25 °C	5000	A ² s
IGBT Chopper			
V _{CEs}		600	V
V _{GES}		± 20	V
I _C	T _{heatsink} = 25 / 80 °C	30 / 20	A
I _{CM}	t _p < 1 ms; T _{heatsink} = 25 / 80 °C	60 / 40	A
Freewheeling Diode ²⁾			
V _{RRM}		600	V
I _F	T _{heatsink} = 25 / 80 °C	57 / 38	A
I _{FM}	t _p < 1 ms; T _{heatsink} = 25 / 80 °C	114 / 76	A
T _j	Diode & IGBT	- 40 ... + 150	°C
T _j	Thyristor	- 40 ... + 125	°C
T _{stg}		- 40 ... + 125	°C
V _{isol}	AC, 1 min.	2500	V

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
Diode - Rectifier					
V _F	I _F = 35 A T _j = 125 °C	-	1,15	-	V
V _{TO}	T _j = 125 °C	-	0,8	-	V
r _T	T _j = 125 °C	-	10	-	mΩ
R _{thjh}	per diode	-	-	1,6	K/W
Thyristor - Rectifier					
V _T	I _F = 75 A T _j = 25 °C	-	-	1,8	V
V _T (TO)	T _j = 125 °C	-	-	1,0	V
r _T	T _j = 125 °C	-	-	10	mΩ
R _{thjh}	per thyristor	-	-	1,3	K/W
I _{GD}	T _j = 125 °C	3	-	-	mA
V _{GT}	T _j = 25 °C	-	-	3	V
I _{GT}		-	-	100	mA
I _H	T _j = 25 °C	-	200	-	mA
I _L		-	400	-	mA
dv/dt _{CR}	T _j = 125 °C	500	-	-	V/μs
di/dt _{CR}		-	-	125	A/μs
IGBT - Chopper					
V _{CEsat}	I _C = 30 A T _j = 25 (125) °C	-	2,1(2,2)	2,7(2,8)	V
t _{d(on)}	V _{CC} = 300 V; V _{GE} = ± 15 V	-	50	100	ns
t _r		I _C = 30 A; T _j = 125 °C	-	80	160
t _{d(off)}	R _{gon} = R _{goff} = 33 Ω	-	250	370	ns
t _f		inductive load	-	500	750
E _{on} + E _{off}		-	4,0	-	mJ
C _{ies}	V _{CE} = 25 V; V _{GE} = 0 V, 1 MHz	-	1,6	-	nF
R _{thjh}	per IGBT	-	-	1,8	K/W

MiniSKiiP 8
SEMIKRON integrated intelligent Power
SKiiP 82 AHB 08
half controlled
3-phase bridge rectifier + IGBT braking chopper

Case M8a



UL recognized file no. E63532

- specification of temperature sensor see part A
- common characteristics see page B 16 – 3

Options

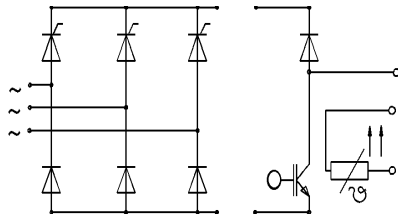
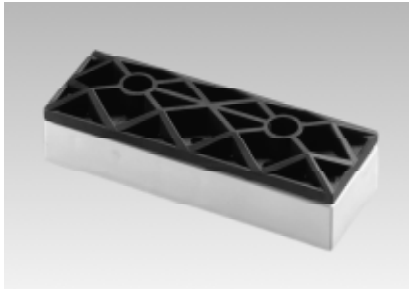
- also available with uncontrolled rectifier (called 82 ANB 08)
- also available with faster IGBTs (type ... 063), data sheet on request

¹⁾ T_{heatsink} = 25 °C, unless otherwise specified

²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast recovery)

MiniSKiiP 8
SEMIKRON integrated
intelligent Power
SKiiP 82 AHB 08
half controlled
3-phase bridge rectifier +
IGBT braking chopper

Case M8a

**SKiiP 82 AHB 08**

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
Diode ²⁾ - Freewheeling					
$V_F = V_{EC}$	$I_F = 50 \text{ A}$ $T_j = 25 (125) \text{ }^\circ\text{C}$	–	1,45(1,4)	1,7(1,7)	V
V_{TO}	$T_j = 125 \text{ }^\circ\text{C}$	–	0,85	0,9	V
r_T	$T_j = 125 \text{ }^\circ\text{C}$	–	11	16	m Ω
I_{RRM}	$I_F = 50 \text{ A}; V_R = -300 \text{ V}$ $di_F/dt = -800 \text{ A}/\mu\text{s}$ $V_{GE} = 0 \text{ V}, T_j = 125 \text{ }^\circ\text{C}$ per diode	–	50	–	A
Q_{rr}		–	5,0	–	μC
E_{off}		–	1,5	–	mJ
R_{thjh}		–	–	1,2	K/W
Temperature Sensor					
R_{TS}	$T = 25 / 100 \text{ }^\circ\text{C}$		1000 / 1670		Ω
Mechanical Data					
M_1	case to heatsink, SI Units	2,5	–	3,5	Nm
Case	mechanical outline see pages B 16 – 13 and B 16 – 14		M8a		

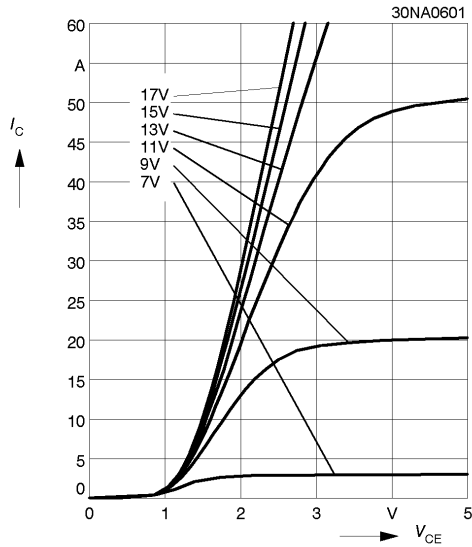


Fig. 1 Typ. output characteristic, $t_p = 80 \mu s$; $25 \text{ }^\circ\text{C}$

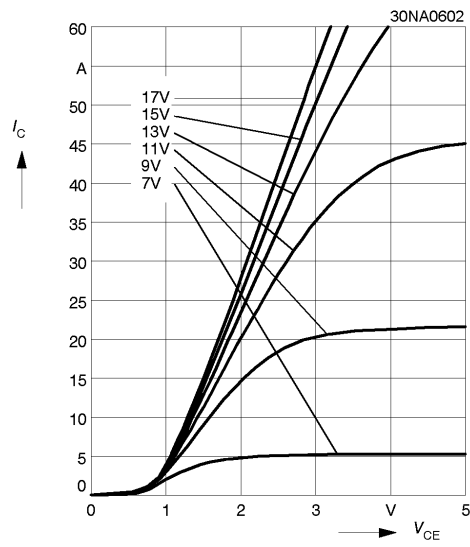


Fig. 2 Typ. output characteristic, $t_p = 80 \mu s$; $125 \text{ }^\circ\text{C}$

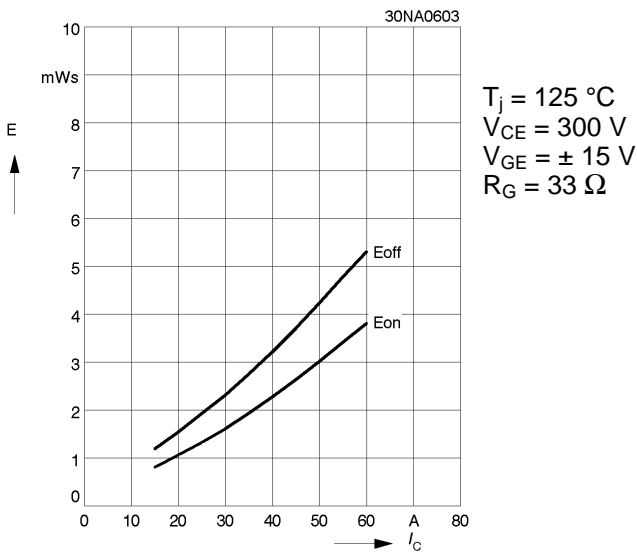


Fig. 3 Turn-on /-off energy = $f(I_c)$

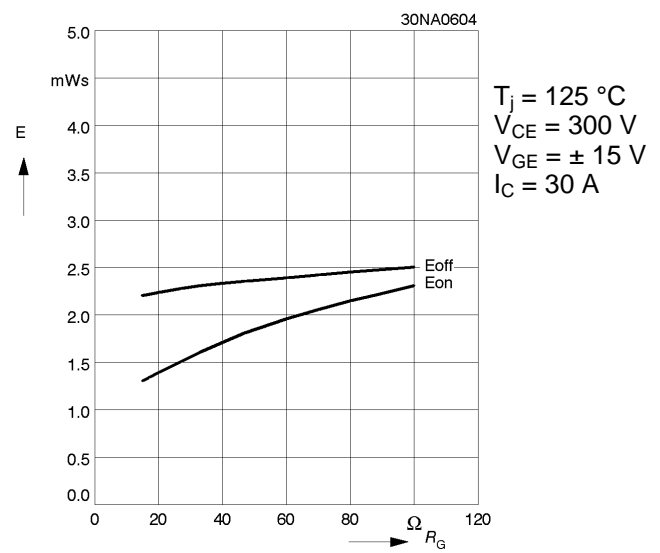


Fig. 4 Turn-on /-off energy = $f(R_G)$

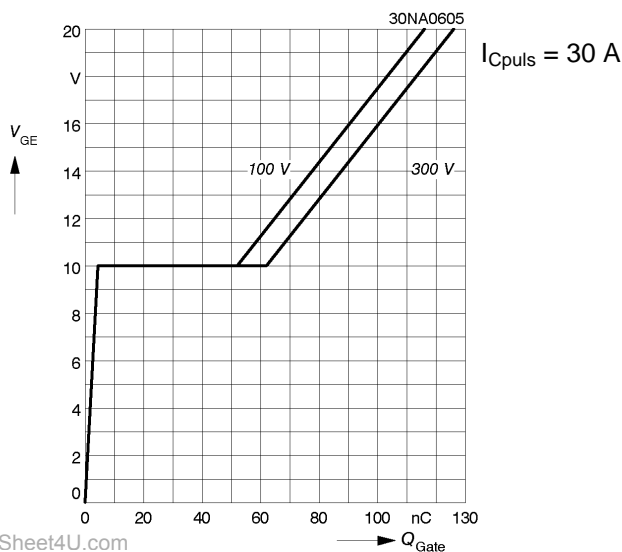


Fig. 5 Typ. gate charge characteristic

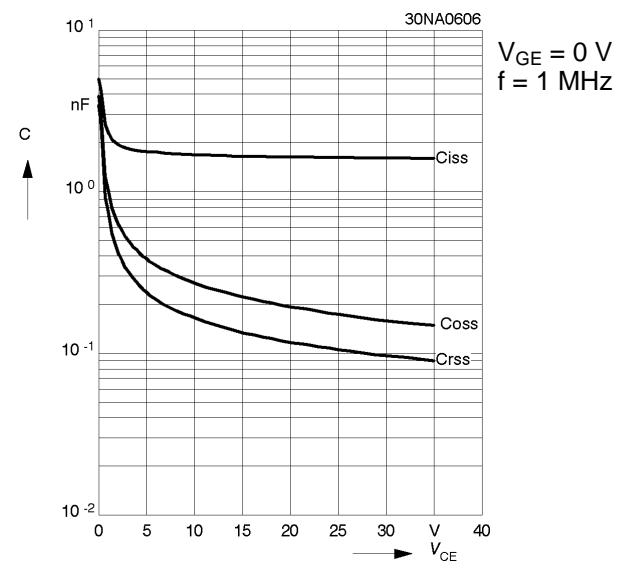


Fig. 6 Typ. capacitances vs. V_{CE}

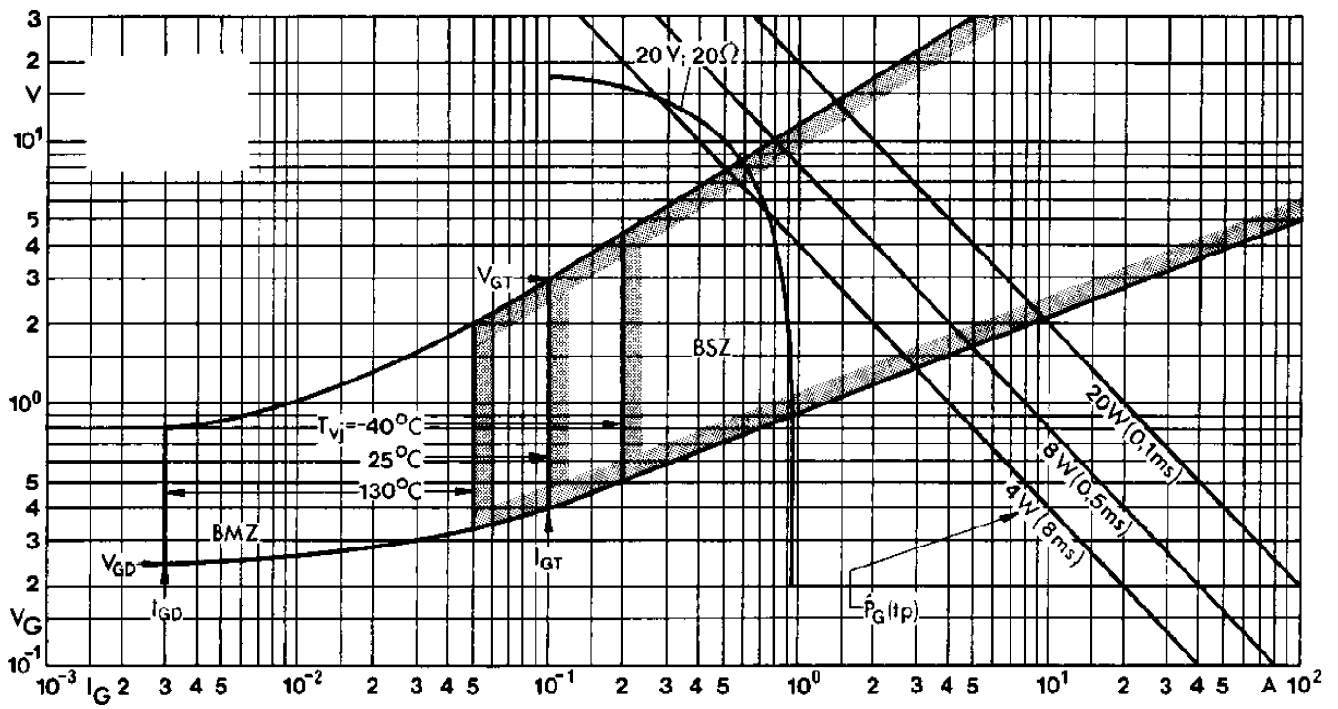


Fig. 7 Gate trigger characteristics

2. Common characteristics of MiniSKiiP

MiniSKiiP 600 V

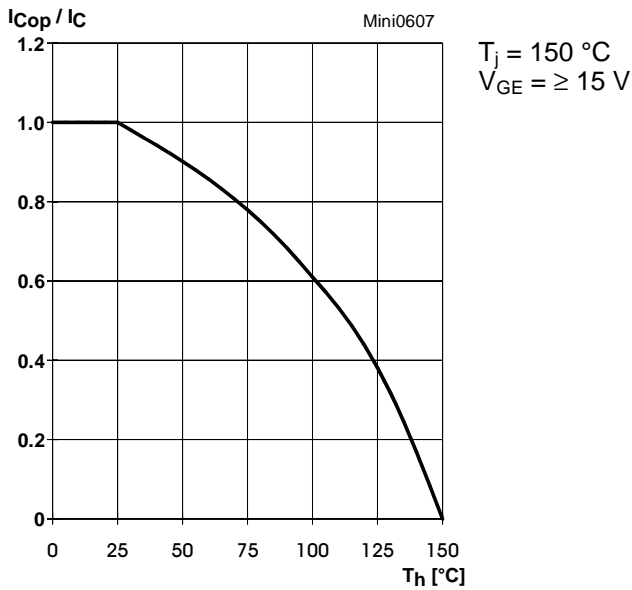


Fig. 7 Rated current of the IGBT $I_{COP} / I_C = f(T_h)$

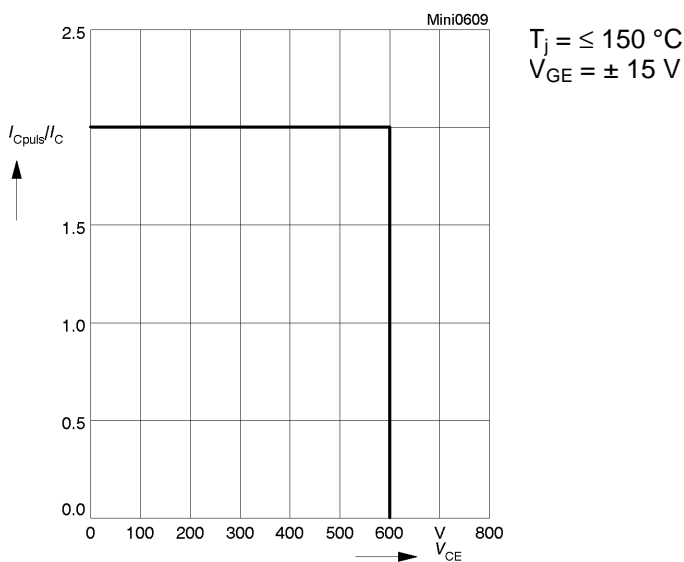


Fig. 9 Turn-off safe operating area (RBSOA) of the IGBT

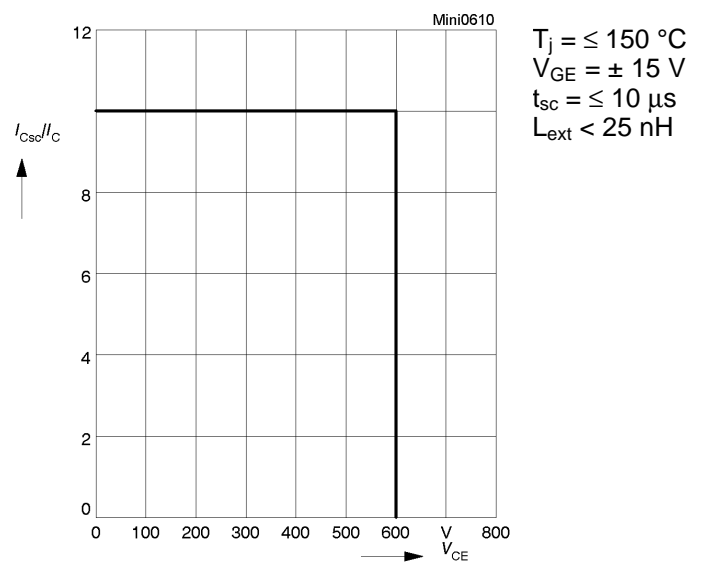


Fig. 10 Safe operating area at short circuit of the IGBT

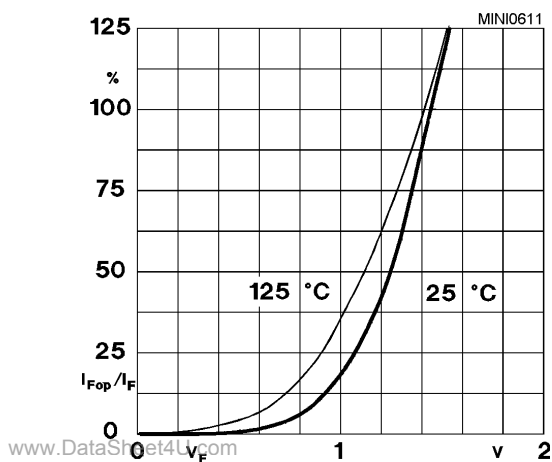


Fig. 11 Typ. freewheeling diode forward characteristic

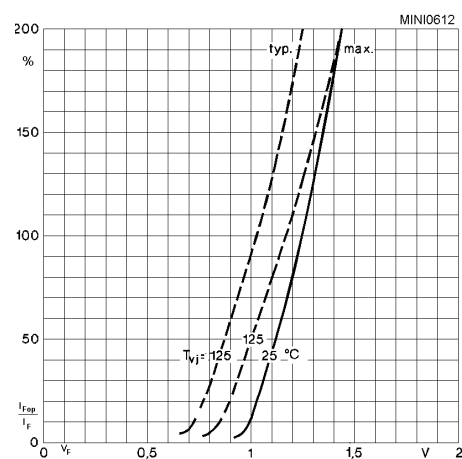


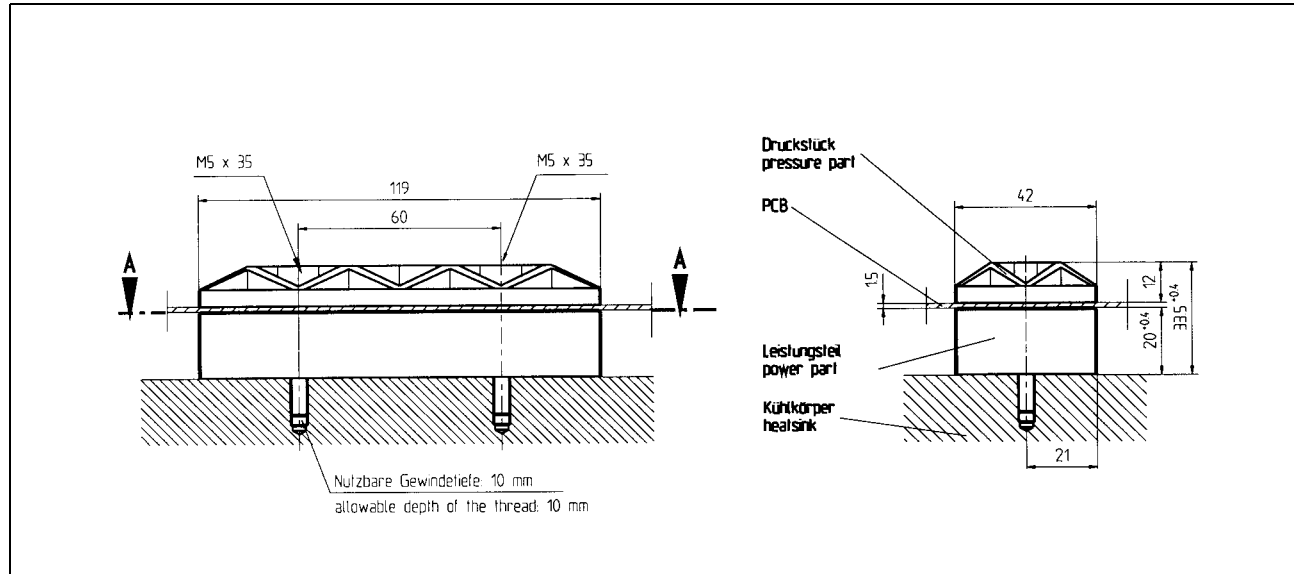
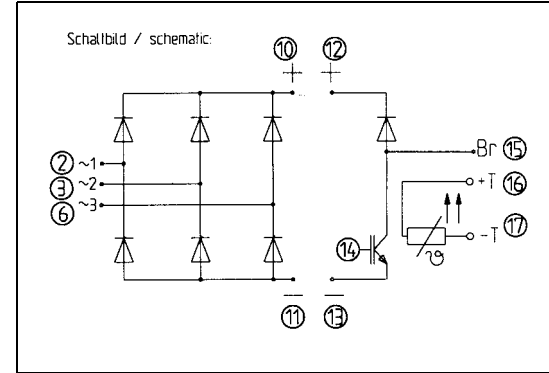
Fig. 12 Forward characteristic of the input bridge diode

MiniSKiiP 8

Input bridge part

- SKiiP 82 ANB 08
- SKiiP 83 ANB 08
- SKiiP 81 ANB 15
- SKiiP 82 ANB 15
- SKiiP 83 ANB 15
- SKiiP 83 AHB 15
- SKiiP 83 ATB 15

Circuit ANB
Case M8a

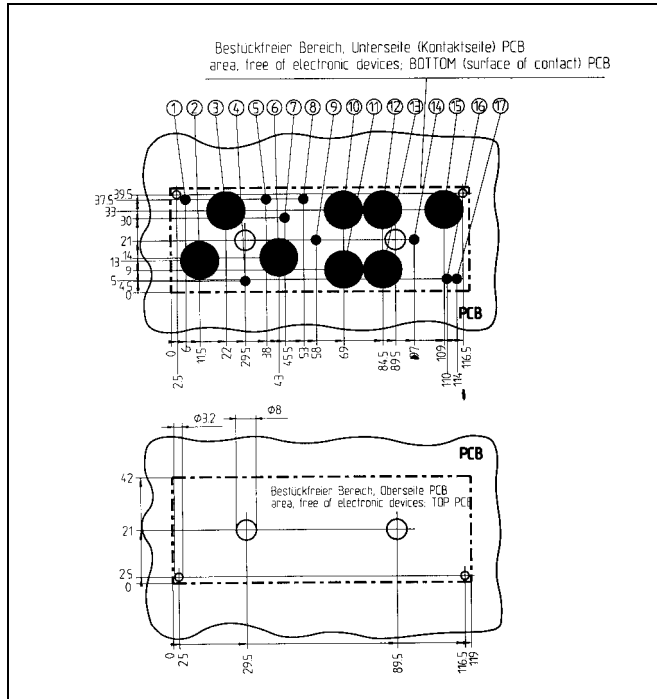


MiniSKiiP 8

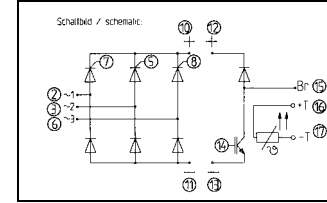
Input bridge part

- SKiiP 82 ANB 08
- SKiiP 83 ANB 08
- SKiiP 81 ANB 15
- SKiiP 82 ANB 15
- SKiiP 83 ANB 15
- SKiiP 83 AHB 15
- SKiiP 83 ATB 15

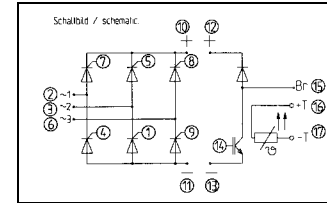
Case M8a
Layout and connections for the customer's printed circuit board



Circuit AHB



Circuit ATB



Pin	Connection			
	Diode bridge ANB	Halfcontrolled AHB	Thyristor bridge ATB	
1	reserved	reserved		G2 Bot
2	~ 1	~ 1	~ 1	
3	~ 2	~ 2	~ 2	
4	reserved	reserved		G1 Bot
5	reserved	G2 Top		G2 Top
6	~ 3	~ 3	~ 3	
7	reserved	G1 Top		G1 Top
8	reserved	G3 Top		G3 Top
9	reserved	reserved		G3 Bot
10	+	+	+	
11	-	-	-	
12	+	+	+	
13	-	-	-	
14	Gate Br	Gate Br		Gate Br
15	Br	Br	Br	
16	T +	T +		T +
17	T -	T -		T -